

BIPOLAR ANALOG INTEGRATED CIRCUIT

μ PC494

SWITCHING REGULATOR CONTROL CIRCUIT

DESCRIPTION

The μ PC494 is an inverter control unit which provides all the control circuitry for PWM type switching regulators. Included in this device is the voltage reference, dual error amplifiers, oscillator, pulse width modulator, pulse steering flip flop, dual alternating output switches and dead-time control.

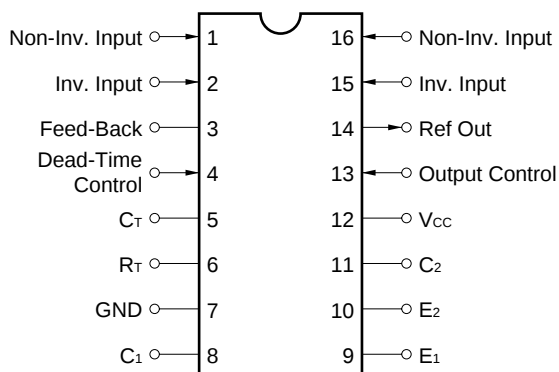
FEATURES

- Complete PWM power control circuit.
- Adjustable dead-time (0 to 100%).
- No double pulsing of same output during load transient condition.
- Dual error amplifiers have wide common mode input voltage capability (-0.3 V to $V_{CC}-2$ V).
- Circuit architecture provides easy synchronization.
- Uncommitted outputs for 250-mA sink or source.
- With miss-operation prevention circuit for low level supply voltage.
- Full pin-compatible TL494C.

★ ORDERING INFORMATION

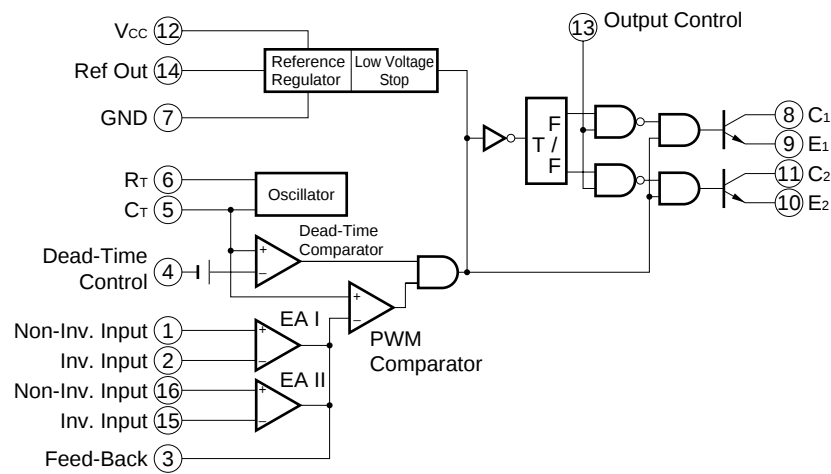
Part Number	Package
μ PC494C	16-pin plastic DIP (7.62 mm (300))
μ PC494G	16-pin plastic SOP (9.53 mm (375))
μ PC494GS	16-pin plastic SOP (7.62 mm (300))

★ PIN CONFIGURATION (Top View)



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Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.

BLOCK DIAGRAM



★ **ABSOLUTE MAXIMUM RATINGS (T_A = 25°C, unless otherwise noted)**

Characteristics	Symbol	μPC494C	μPC494G	μPC494GS	Unit
Supply Voltage	V _{CC}	−0.3 to +41	−0.3 to +41	−0.3 to +41	V
Error Amplifier Input Voltage	V _{ICM}	−0.3 to V _{CC} + 0.3	−0.3 to V _{CC} + 0.3	−0.3 to V _{CC} + 0.3	V
Output Voltage	V _{CER}	−0.3 to +41	−0.3 to +41	−0.3 to +41	V
Output Current	I _C	250	250	250	mA
Total Power Dissipation	P _T	1000	780 ^{Note}	650 ^{Note}	mW
Operating Ambient Temperature	T _A	−20 to +85	−20 to +85	−20 to +85	°C
Storage Temperature	T _{stg}	−65 to +150	−65 to +150	−65 to +150	°C

Note With 25 cm² x 1.6 mm glass-epoxy substrate.

- ★ **Caution** Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

RECOMMENDED OPERATING CONDITIONS

Characteristics	Symbol	MIN.	TYP.	MAX.	Unit
Supply Voltage	V _{CC}	7		40	V
Output Voltage	V _{CER}	−0.3		40	V
Output Current	I _C			200	mA
Error Amplifier Sink Current	I _{OAMP}			−0.3	mA
Timing Capacitor	C _T	0.47		10000	nF
Timing Resistance	R _T	1.8		500	kΩ
Oscillation Frequency	f _{OSC}	1		300	kHz
Operating Temperature	T _{opt}	−20		+70	°C

- ★ **Caution** The recommended operating range may be exceeded without causing any problems provided that the absolute maximum ratings are not exceeded. However, if the device is operated in a way that exceeds the recommended operating conditions, the margin between the actual conditions of use and the absolute maximum ratings is small, and therefore thorough evaluation is necessary. The recommended operating conditions do not imply that the device can be used with all values at their maximum values.

★ ELECTRICAL SPECIFICATIONS ($V_{CC} = 15\text{ V}$, $f = 10\text{ kHz}$, $-20 \leq T_A \leq +70^\circ\text{C}$, unless otherwise noted)

(1/2)

Block	Characteristics		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Reference Section	Output Voltage		V_{REF}	$I_{REF} = 1\text{ mA}$, $T_A = 25^\circ\text{C}$	4.75	5	5.25	V
	Line Regulation		REG_{IN}	$7\text{ V} \leq V_{CC} \leq 40\text{ V}$, $I_{REF} = 1\text{ mA}$, $T_A = 25^\circ\text{C}$		8	25	mV
	Load Regulation		REG_L	$1\text{ mA} \leq I_{REF} \leq 10\text{ mA}$, $T_A = 25^\circ\text{C}$		1	15	mV
	Temperature Coefficient		$\Delta V_{REF} / \Delta T$	$-20^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$, $I_{REF} = 1\text{ mA}$		0.01	0.03	%/ $^\circ\text{C}$
	Short Circuit Output Current ^{Note1}		I_{SHORT}	$V_{REF} = 0\text{ V}$		50		mA
Oscillator Section	Frequency		f_{OSC}	$C_T = 0.01\text{ }\mu\text{F}$, $R_T = 12\text{ k}\Omega$, $T_A = 25^\circ\text{C}$		10		kHz
	Standard Deviation of Frequency ^{Note2}			$7\text{ V} \leq V_{CC} \leq 40\text{ V}$, $T_A = 25^\circ\text{C}$, C_T , R_T , const.		10		%
	Frequency Change with Temperature			$0^\circ\text{C} \leq T_A \leq 70^\circ\text{C}$, $C_T = 0.01\text{ }\mu\text{F}$, $R_T = 12\text{ k}\Omega$		1	2	%
	Frequency Change with Voltage			$7\text{ V} \leq V_{CC} \leq 40\text{ V}$, $T_A = 25^\circ\text{C}$, $C_T = 0.01\text{ }\mu\text{F}$, $R_T = 12\text{ k}\Omega$		1		%
Dead-Time Control Section	Input Bias Current			$0\text{ V} \leq V_i \leq 5.25\text{ V}$		-2	-10	μA
	Maximum Duty Cycle (Each Output)			$V_i = 0\text{ V}$	45	49		%
	Input Threshold Voltage 1		V_{TH1}	Output pulse 0% duty cycle		3	3.3	V
	Input Threshold Voltage 2		V_{TH2}	Output pulse maximum duty cycle	0			V
Error Amplifier Section	Input Offset Voltage		V_{IO}	$V_{OAMP} = 2.5\text{ V}$		2	10	mV
	Input Offset Current		I_{IO}	$V_{OAMP} = 2.5\text{ V}$		25	250	nA
	Input Bias Current			$V_{OAMP} = 2.5\text{ V}$		0.2	1	μA
	Common Mode Input Voltage	Low	V_{ICM}	$7\text{ V} \leq V_{CC} \leq 40\text{ V}$	-0.3			V
		High			$V_{CC}-2$			
	Open Loop Voltage Amplification		A_V	$V_{OAMP} = 0.5\text{ to }3.5\text{ V}$, $T_A = 25^\circ\text{C}$	60	80		dB
	Unity Gain Bandwidth			$T_A = 25^\circ\text{C}$	500	830		kHz
	Common Mode Rejection Ratio		CMR	$V_{CC} = 40\text{ V}$, $T_A = 25^\circ\text{C}$	65	80		dB
	Output Sink Current			$V_{OAMP} = 0.7\text{ V}$	0.3	0.7		mA
PWM Section	Input Threshold Voltage (3-pin)			Output pulse 0% duty cycle, see Figure 1 .		4	4.5	V
	Input Sink Current			$V_{(pin\ 3)} = 0.7\text{ V}$	0.3	0.7		mA

Remark The TYP. values are values at $T_A = 25^\circ\text{C}$, except for the characteristics of temperature.

(2/2)

Block	Characteristics		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output Section	Collector Cut-off Current		I _{CER}	V _{CE} = 40 V, V _{CC} = 40 V, Common Emitter			100	μA
	Emitter Cut-off Current			V _{CC} = V _C = 40 V, V _E = 0 V, Emitter Follower			−100	μA
	Collector Saturation Voltage	Common Emitter	V _{CE(sat)}	I _C = 200 mA, V _E = 0 V		0.95	1.3	V
		Emitter Follower	V _{CE(ON)}	I _E = −200 mA, V _C = 15 V		1.6	2.5	V
	Output Voltage Rise Time	Common Emitter	t _{r1}	V _{CC} = 15 V, R _L = 150 Ω, I _C ≅ 100 mA, T _A = 25°C, see Figure 1.		100	200	ns
	Output Voltage Fall Time		t _{f1}			70	200	ns
	Output Voltage Rise Time	Emitter Follower	t _{r2}	V _C = 15 V, R _L = 150 Ω, I _E ≅ 100 mA, T _A = 25°C, see Figure 1.		100	200	ns
	Output Voltage Fall Time		t _{f2}			70	200	ns
Total Device	Standby Current		I _{CC(S,B)}	V _{CC} = 15 V, all other pins open.		8	12.5	mA
	Bias Current		I _{CC(BI)}	V _(pin 4) = 2 V, see Figure 1.		10		mA

Remark The TYP. values are values at T_A = 25°C, except for the characteristics of temperature.

Notes 1. The short circuit output current flows for no more than 1 second. Repeat operation is possible if the internal heat accumulation is not within a harmful range.

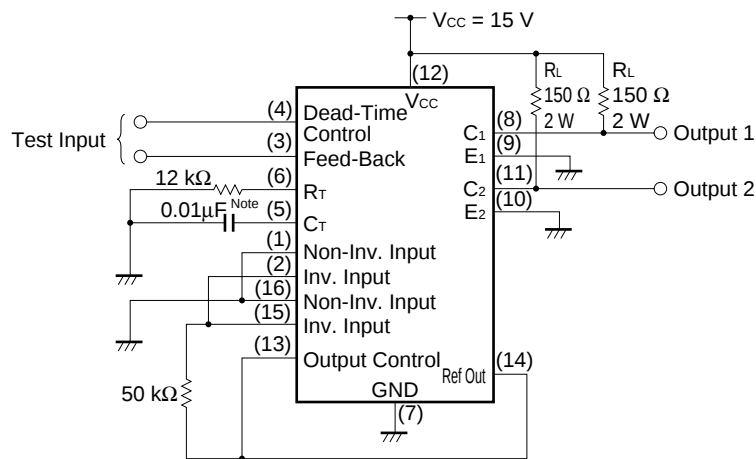
2. Standard deviation is a measure of the statistical distribution about the mean as derived from the formula ;

$$\sigma = \sqrt{\frac{\sum_{n=1}^N (X_n - \bar{X})^2}{N - 1}}$$

Calculation expression of frequency f_{osc} is as follows ;

$$f_{osc} \cong \frac{1}{0.817 R_T \cdot C_T + 1.42 \cdot 10^{-6}} \text{ (Hz)} \quad [R_T] = \Omega, [C_T] = F$$

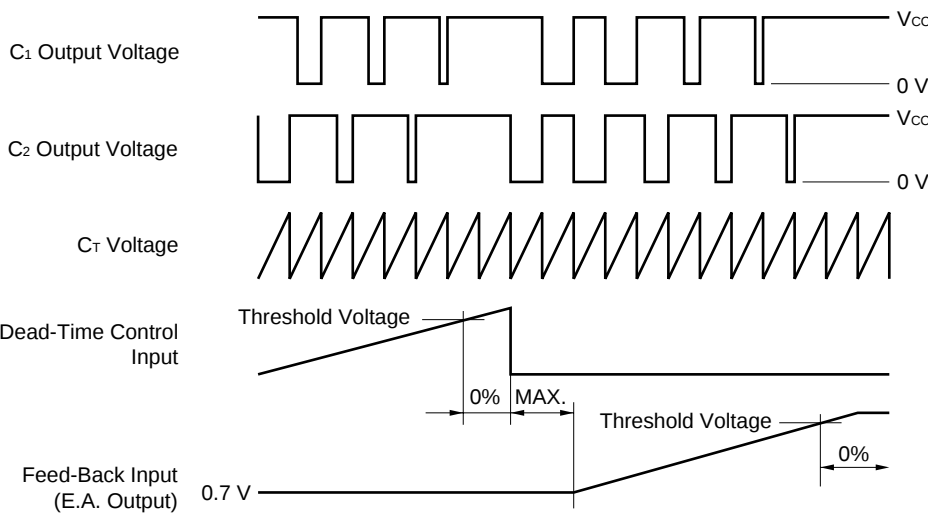
Figure1. Test Circuit



Note Recommend film capacitor.

★ **Caution** When the emitter follower is output, connect C₁ and C₂ to V_{cc} and E₁ and E₂ to GND via R_L.

Figure2. Voltage Waveform

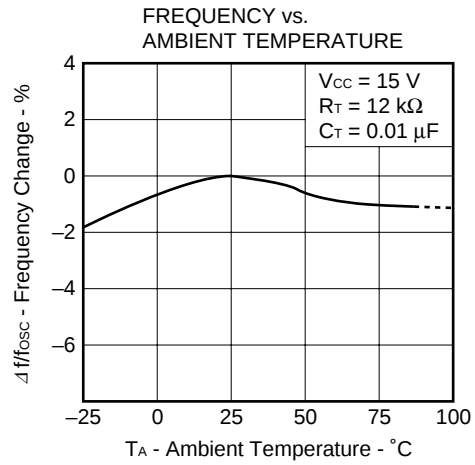
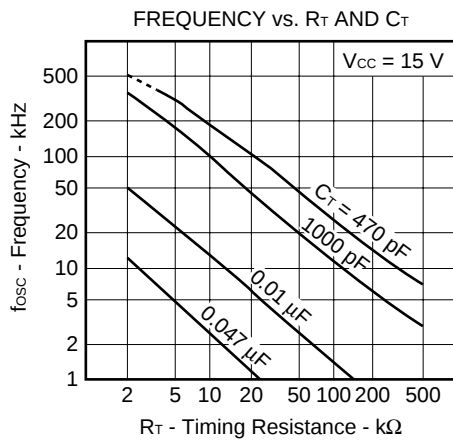
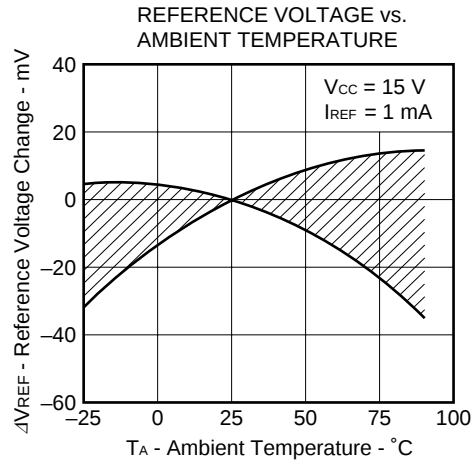
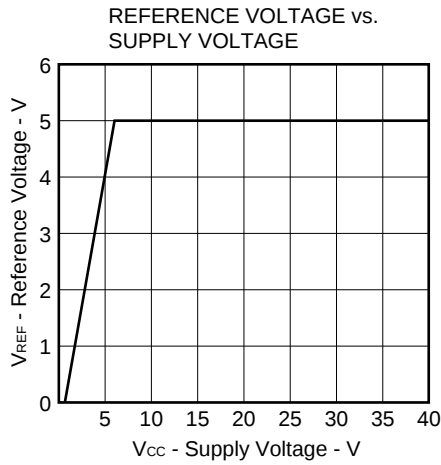
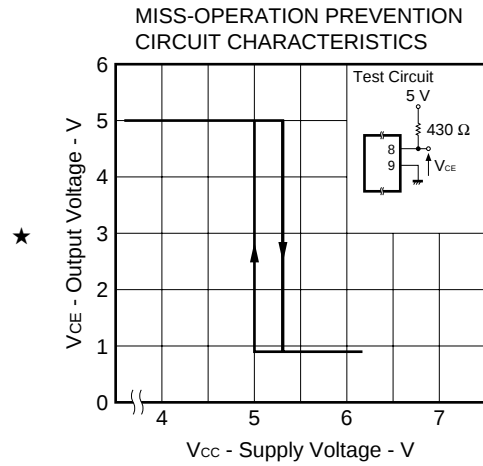
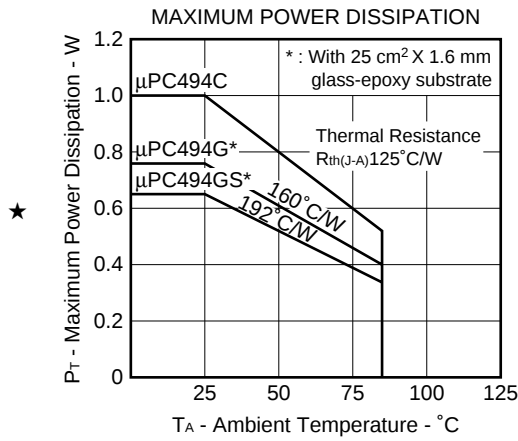


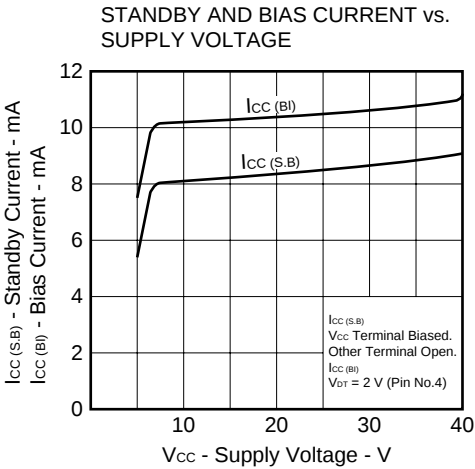
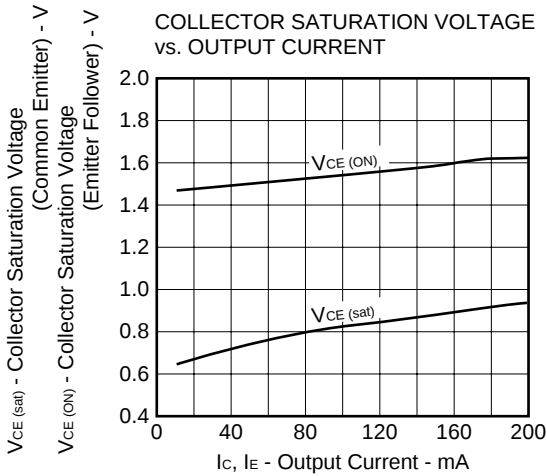
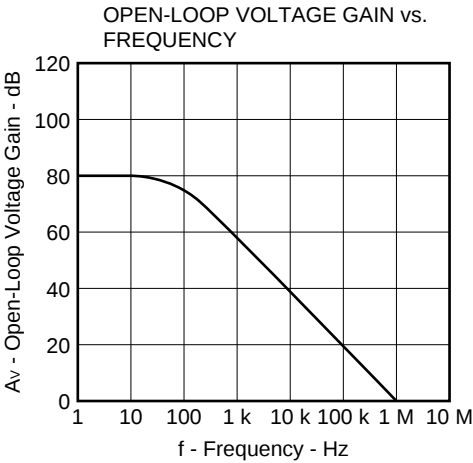
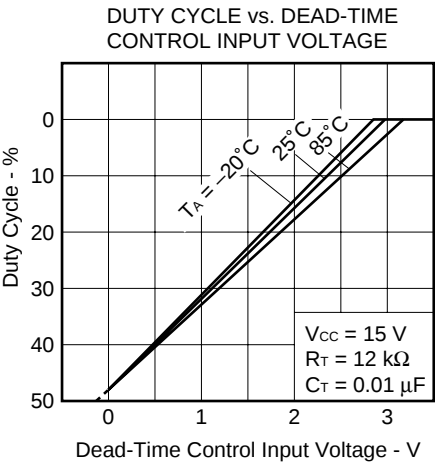
Connection of Output Control Pin (Pin No.13)

Output Control Input (Pin No.13)	Operation Mode
At Ref Out	Normal push-pull operation
Grounded	Single-ended or parallel output

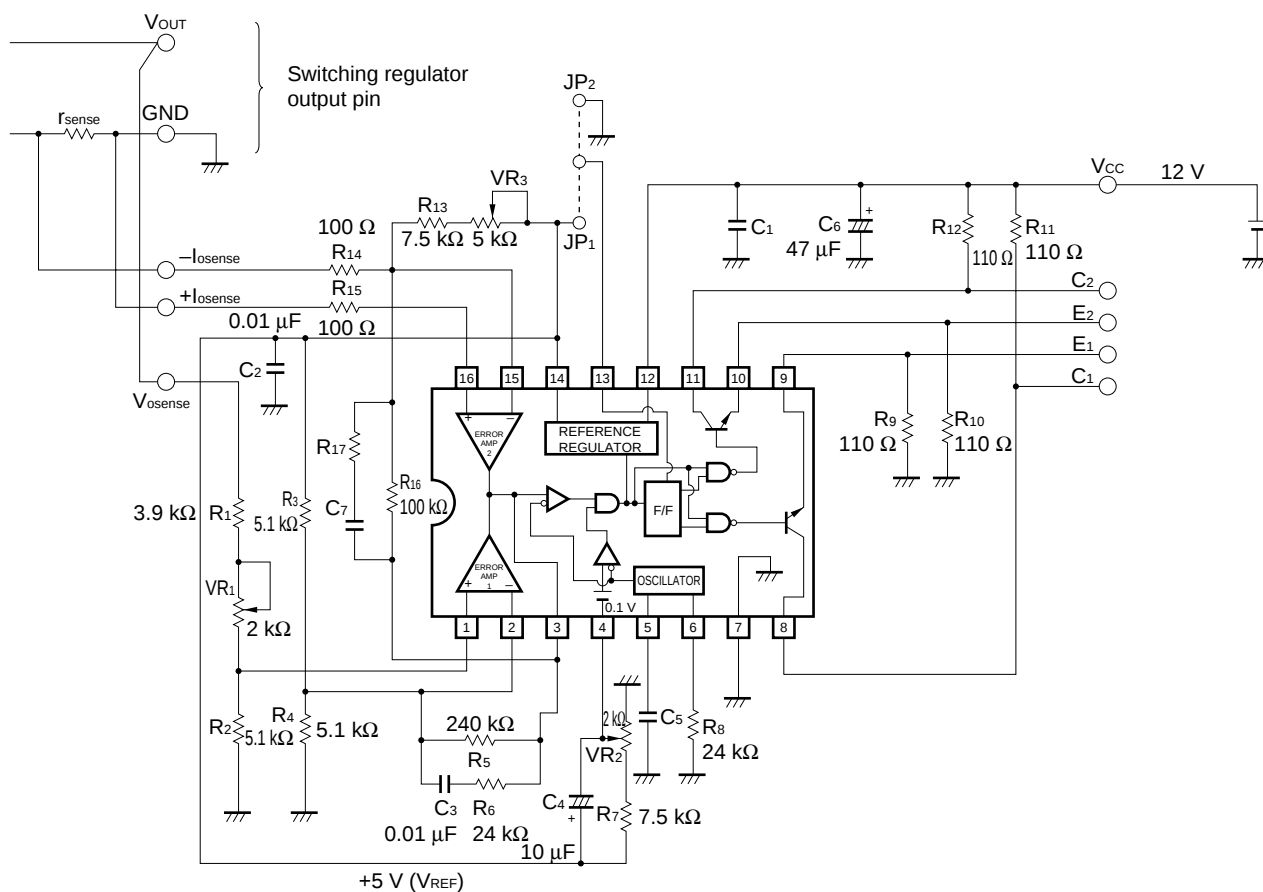
TYPICAL PERFORMANCE CHARACTERISTICS

★ (Unless otherwise specified, $T_A = 25^\circ\text{C}$, $V_{CC} = 15\text{ V}$, Reference)



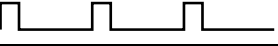
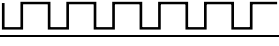


BASIC APPLICATION CIRCUIT

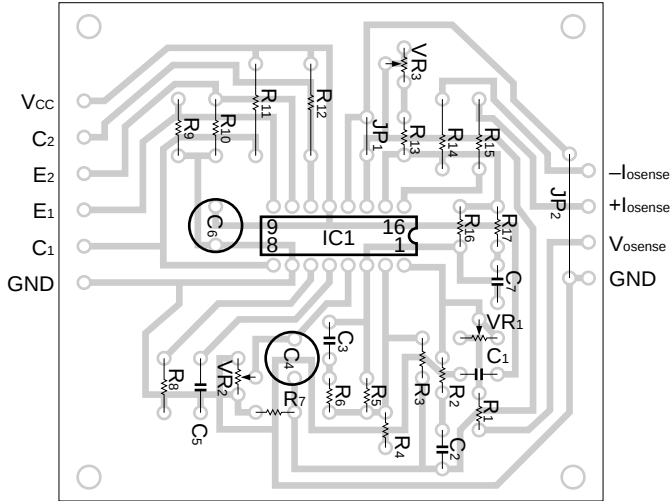


★ **Remark** $f_{osc} \cong 40 \text{ kHz}$, $C_5 = 1000 \text{ pF}$ (Recommend film capacitor)

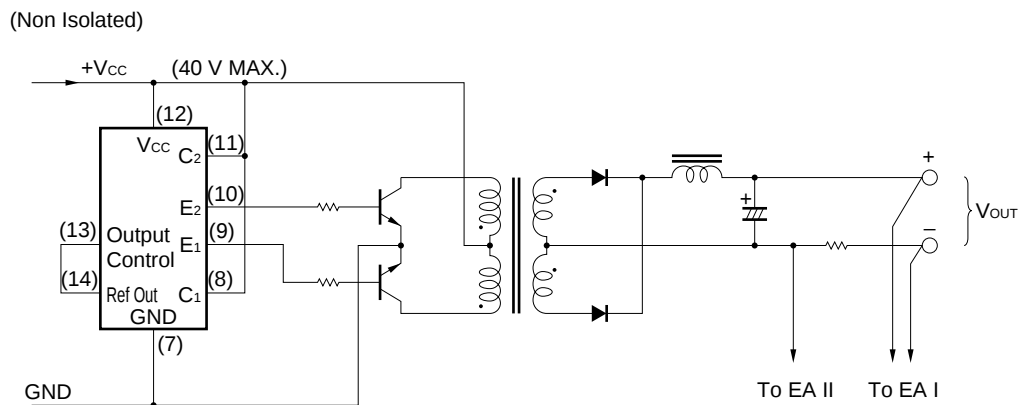
CONNECTION DIAGRAM

Operation Mode	Output Control Input (Pin No.13)	Output Mode	Output Voltage Waveform
Push-pull operation	At Ref-out (JP1 Wired)	Open collector ($R_9, R_{10} \ 0\Omega$)	C1 
		Emitter follower ($R_{11}, R_{12} \ 0\Omega$)	E1  E2 
Single-ended or parallel output	Grounded (JP2 Wired)	Open collector ($R_9, R_{10} \ 0\Omega$)	C1, C2 
		Emitter follower ($R_{11}, R_{12} \ 0\Omega$)	E1, E2 

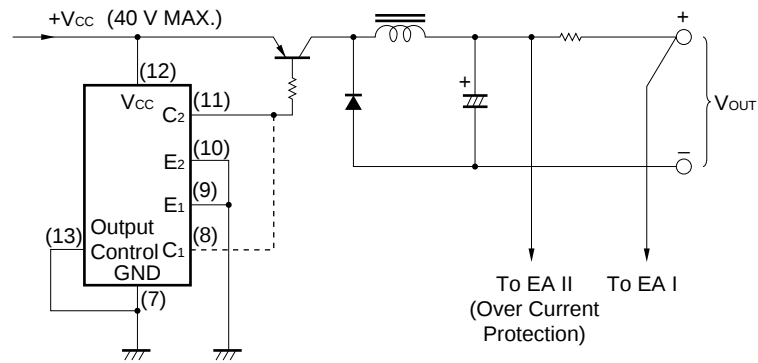
Printed Pattern (Example of μPC494C) (Pattern side, Actual size)



1) Forward Type



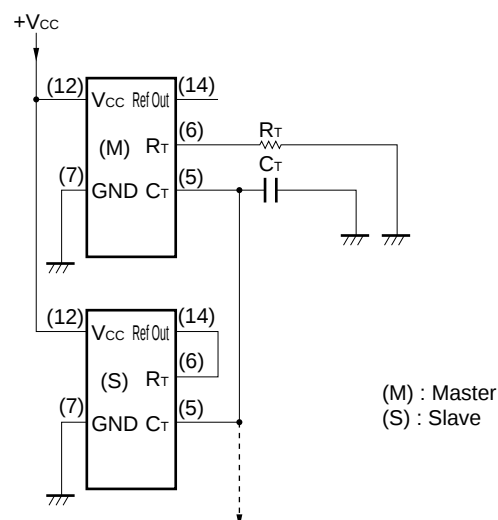
3) Step-down Chopper



Remark The dotted line indicates the connection in case of large current.

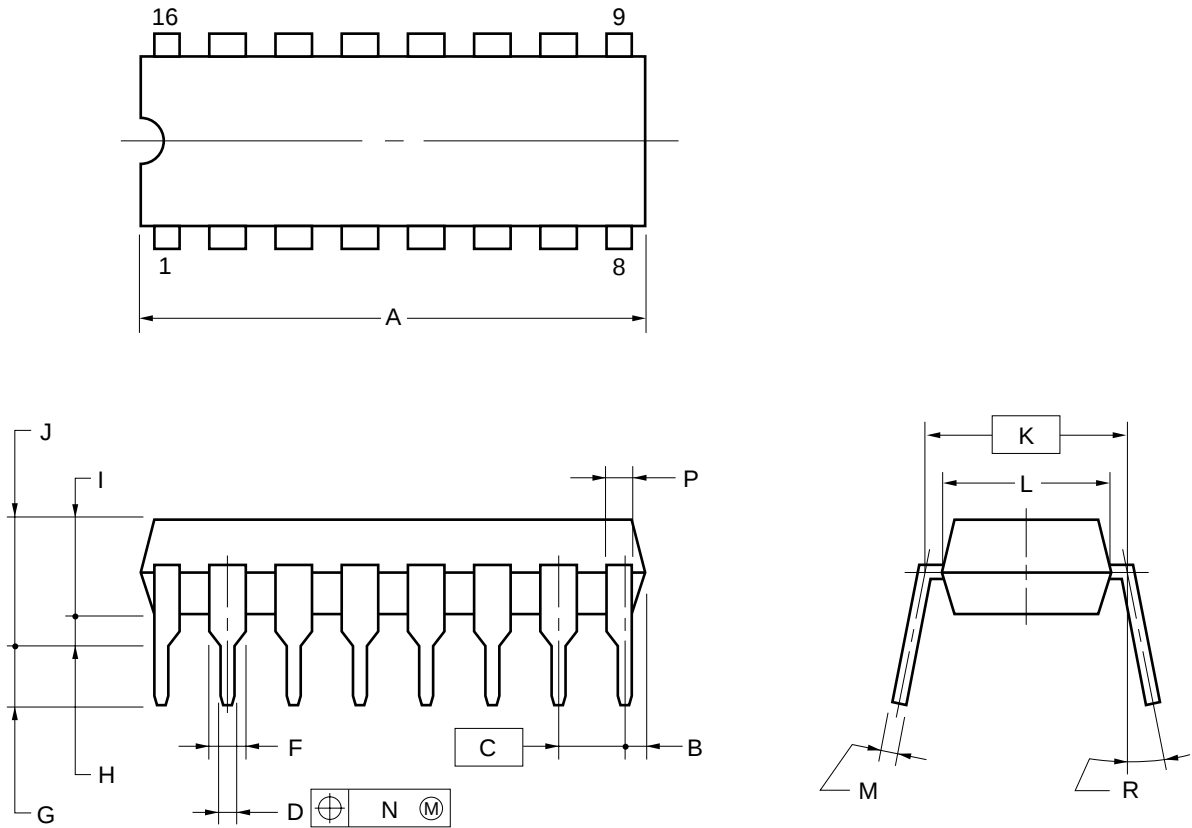
SYNCHRONIZED OPERATION

If synchronized operation is needed, master-slave circuit can be used. This circuit is shown below. Initially, τ_1 terminal of slave IC is connected to pin 14(Ref Out) and internal oscillator is stopped.



★ PACKAGE DRAWINGS (Unit : mm)

16-PIN PLASTIC DIP (7.62mm(300))



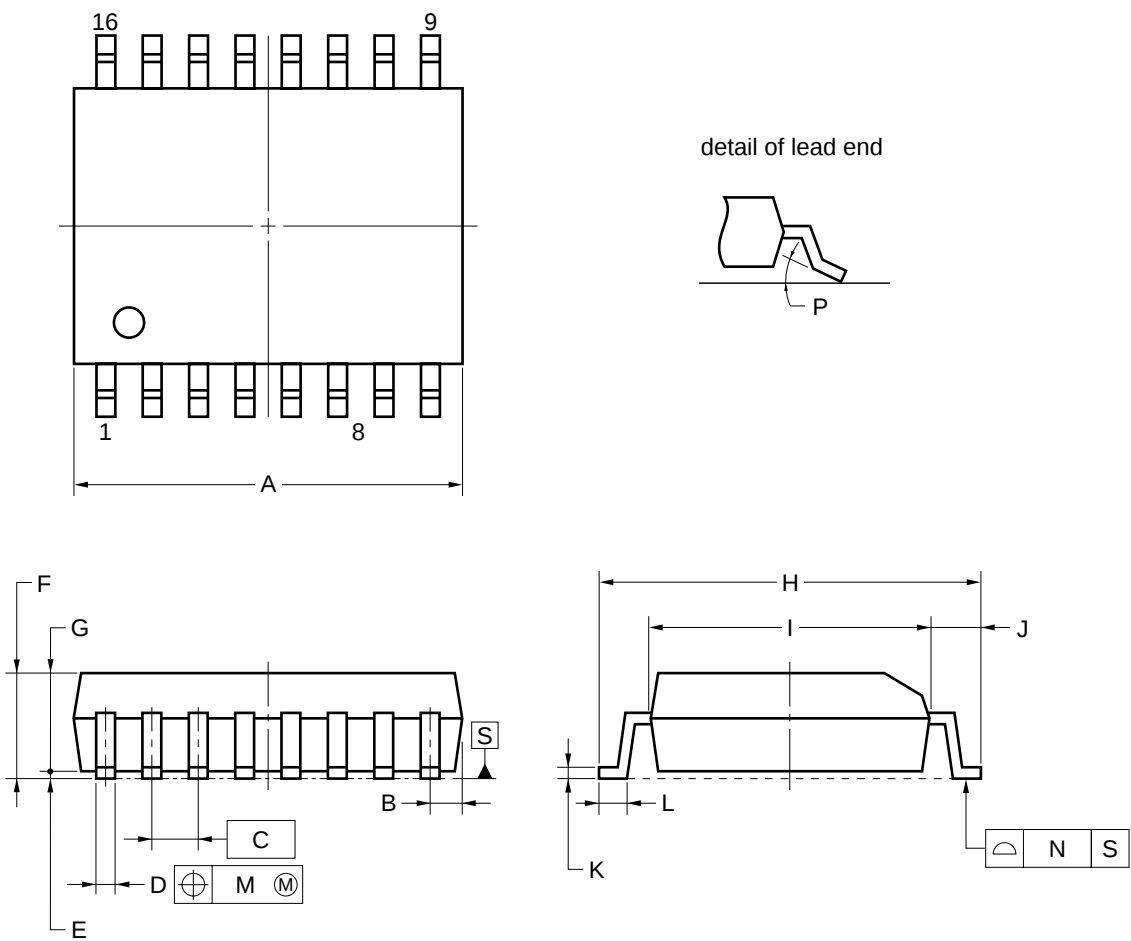
NOTES

1. Each lead centerline is located within 0.25 mm of its true position (T.P.) at maximum material condition.
2. Item "K" to center of leads when formed parallel.

ITEM	MILLIMETERS
A	20.32 MAX.
B	1.27 MAX.
C	2.54 (T.P.)
D	0.50±0.10
F	1.1 MIN.
G	3.5±0.3
H	0.51 MIN.
I	4.31 MAX.
J	5.08 MAX.
K	7.62 (T.P.)
L	6.5
M	0.25 ^{+0.10} _{-0.05}
N	0.25
P	1.1 MIN.
R	0~15°

P16C-100-300B-2

16-PIN PLASTIC SOP (9.53 mm (375))

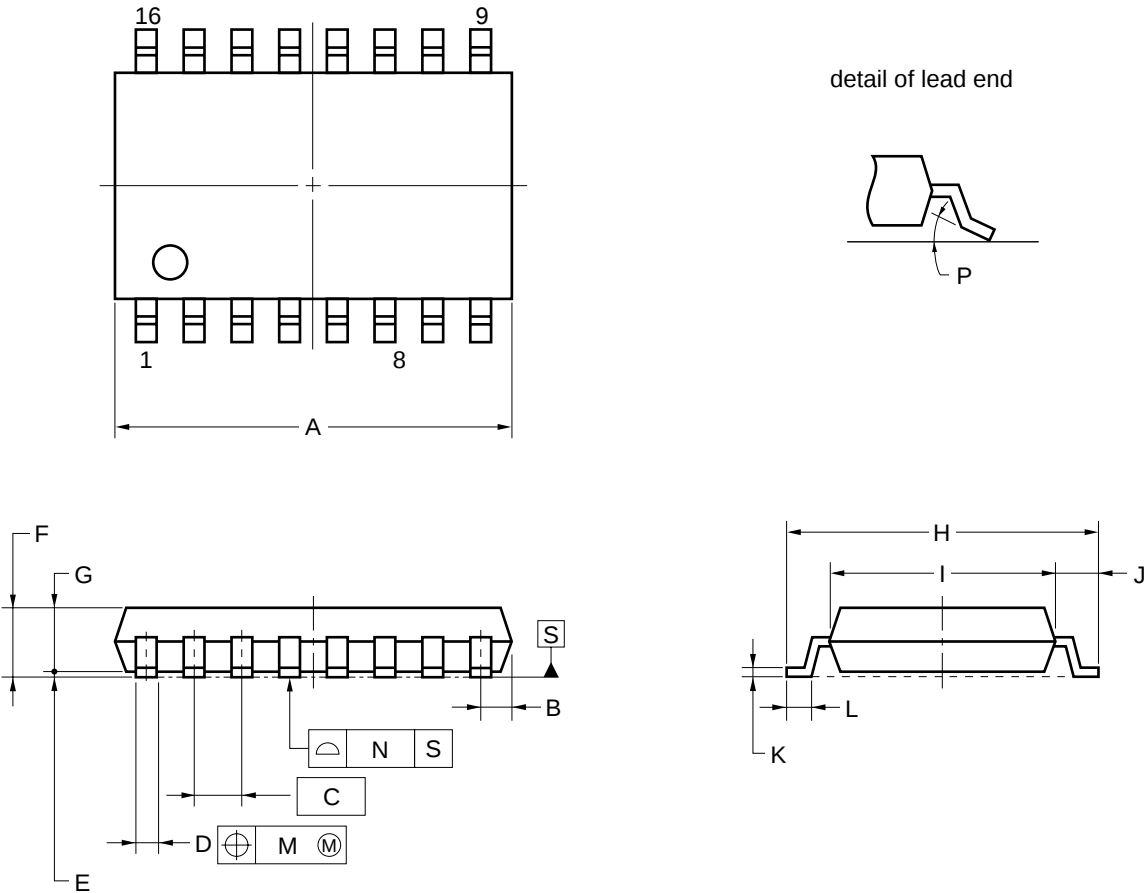


NOTE
Each lead centerline is located within 0.12 mm of its true position (T.P.) at maximum material condition.

ITEM	MILLIMETERS
A	10.0±0.2
B	0.78 MAX.
C	1.27 (T.P.)
D	0.42 ^{+0.08} _{-0.07}
E	0.125±0.075
F	2.77 MAX.
G	2.47±0.1
H	10.3±0.3
I	7.2
J	1.6
K	0.17 ^{+0.08} _{-0.07}
L	0.8±0.2
M	0.12
N	0.15
P	3° ^{+7°} _{-3°}

P16GM-50-375B-6

16-PIN PLASTIC SOP (7.62 mm (300))



NOTE
Each lead centerline is located within 0.12 mm of its true position (T.P.) at maximum material condition.

ITEM	MILLIMETERS
A	10.2±0.2
B	0.78 MAX.
C	1.27 (T.P.)
D	0.42 ^{+0.08} _{-0.07}
E	0.1±0.1
F	1.65±0.15
G	1.55
H	7.7±0.3
I	5.6±0.2
J	1.1±0.2
K	0.22 ^{+0.08} _{-0.07}
L	0.6±0.2
M	0.12
N	0.10
P	3° ^{+7°} _{-3°}

P16GM-50-300B-6

★ RECOMMENDED SOLDERING CONDITIONS

When soldering this product, it is highly recommended to observe the conditions as shown below. If other soldering processes are used, or if the soldering is performed under different conditions, please make sure to consult with our sales offices.

For more details, refer to our document "SEMICONDUCTOR DEVICE MOUNTING TECHNOLOGY MANUAL"(C10535E).

Type of Through-hole Device

μPC494C: 16-pin plastic DIP (7.62 mm (300))

Process	Conditions
Wave Soldering (only to leads)	Solder temperature: 260°C or below, Flow time: 10 seconds or less.
Partial Heating Method	Pin temperature: 300°C or below, Heat time: 3 seconds or less (per each lead).

Caution For through-hole device, the wave soldering process must be applied only to leads, and make sure that the package body does not get jet soldered.

Type of Surface Mount Device

μPC494G: 16-pin plastic SOP (9.53 mm (375))

μPC494GS: 16-pin plastic SOP (7.62 mm (300))

Process	Conditions	Symbol
Infrared Ray Reflow	Peak temperature: 230°C or below (Package surface temperature), Reflow time: 30 seconds or less (at 210°C or higher), Maximum number of reflow processes: 1 time.	IR30-00-1
Vapor Phase Soldering	Peak temperature: 215°C or below (Package surface temperature), Reflow time: 40 seconds or less (at 200°C or higher), Maximum number of reflow processes: 1 time.	VP15-00-1
Wave Soldering	Solder temperature: 260°C or below, Flow time: 10 seconds or less, Maximum number of flow processes: 1 time, Pre-heating temperature: 120°C or below (Package surface temperature).	WS60-00-1
Partial Heating Method	Pin temperature: 300°C or below, Heat time: 3 seconds or less (Per each side of the device).	—

Caution Apply only one kind of soldering condition to a device, except for "partial heating method", or the device will be damaged by heat stress.

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